

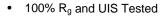
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N-Channel 100 V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
100	0.015 at V _{GS} = 10 V	19		

FEATURES



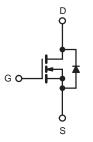




RoHS

APPLICATIONS

- Synchronus Rectification in DC/DC and AC/DC Converters
- Industrial and Motor Drive applications



N-Channel MOSFET

501-223
DOGGS

COT 222

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V_{DS}	100	V	
Gate-Source Voltage		V_{GS}	± 20	v	
Continuous Drain Current (T _J = 175 °C) ^a	T _A = 25 °C	- I _D	19		
Continuous Drain Current (1) = 175 C)	T _A = 70 °C		13	A	
Pulsed Drain Current		I _{DM}	76		
Avalanche Current		I _{AS}	7.8		
Single Pulse Avalanche Energy		E _{AS}	55	mJ	
Maximum Power Dissipation ^a	T _A = 25 °C	- P _D	19.5	W	
	T _A = 70 °C		12.5		
Operating Junction and Storage Temperature Range		T_J , T_{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	t ≤ 10 s	R _{thJA}	30	45	°C/W	
Maximum Junction-to-Ambient	Steady State		50	65		
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	7.5	20		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	-						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	100			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	J 250 A		26		mV/°C	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	I _D = 250 μA		5.6			
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.5		3.5	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
	I _{DSS}	$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 \text{ °C}$			1	μΑ	
Zero Gate Voltage Drain Current					10		
On-State Drain Current ^a	I _{D(on)}	V _{DS} = 5 V, V _{GS} = - 10 V	19			Α	
	Б	V _{GS} = 10 V, I _D =7 A		0.015	0.020	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} =4.5 V, I _D = 5 A		0.027	0.035		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 7 A		17		S	
Dynamic ^b							
Input Capacitance	C _{iss}			1013		pF	
Output Capacitance	C _{oss}	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		212			
Reverse Transfer Capacitance	C _{rss}			85			
T. 10 (0)	Qg	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 7 \text{ A}$	19				
Total Gate Charge		V _{DS} = 50 V, V _{GS} = 4.5 V, I _D = 5 A		11		nC	
Gate-Source Charge	Q_{gs}			9			
Gate-Drain Charge	Q_{gd}			15			
Gate Resistance	R_g	f = 1 MHz		1.6		Ω	
Turn-On Delay Time	t _{d(on)}			7			
Rise Time	t _r	$V_{DS} = 50 \text{ V}, R_L = 15 \Omega$		9		ns	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 7 \text{ A}, V_{GS} = 10 \text{ V}, R_g = 1 \Omega$		18			
Fall Time	t _f			12			
Turn-On Delay Time	t _{d(on)}			10			
Rise Time	t _r	$V_{DS} = 50 \text{ V}, R_L = 15 \Omega$		13			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 5$ A, $V_{GS} = 4.5$ V, $R_g = 1$ Ω		21			
Fall Time	t _f			16			
Drain-Source Body Diode Characteristic	s						
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C			19	A	
Pulse Diode Forward Current ^a	I _{SM}				76		
Body Diode Voltage	V_{SD}	I _S = 1 A		0.5	1.0	V	
Body Diode Reverse Recovery Time	t _{rr}			40		ns	
Body Diode Reverse Recovery Charge	Q _{rr}			35		nC	
Reverse Recovery Fall Time	t _a	$I_F = 7 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$		12			
Reverse Recovery Rise Time	t _b	\neg		10		ns	

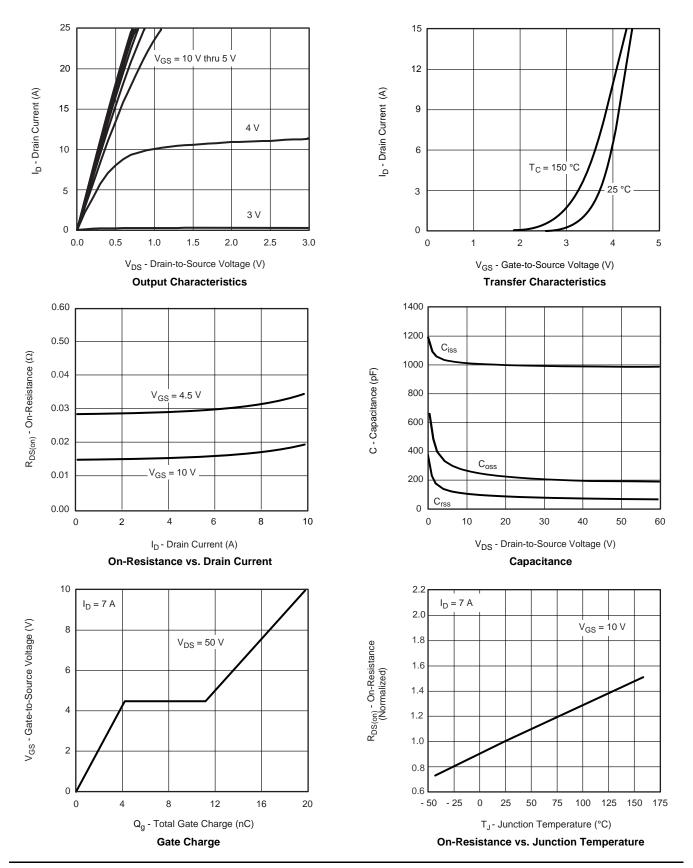
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$ b. Guaranteed by design, not subject to production testing.



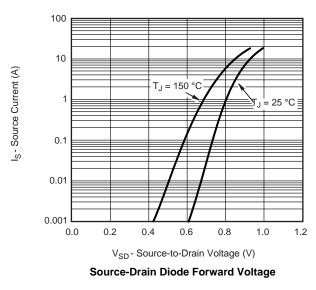


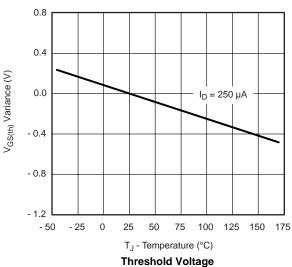
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

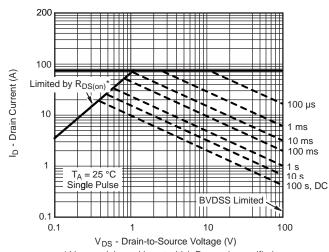




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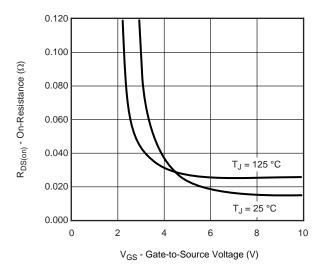




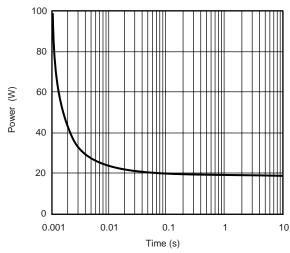


* $V_{GS} > \mbox{minimum } V_{GS}$ at which $R_{DS(on)}$ is specified

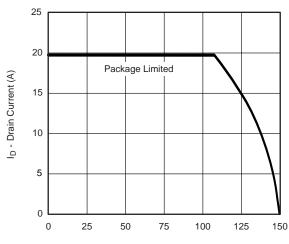
Safe Operating Area, Junction-to-Ambient



On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power, Junction-to-Ambient



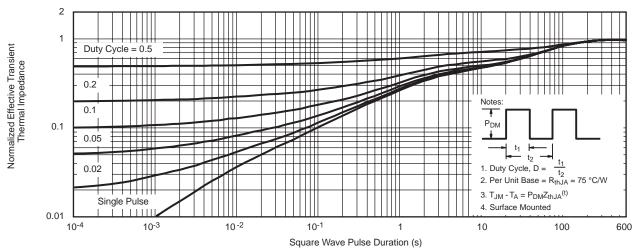
T_C - Case Temperature (°C)

Current Derating*



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient

^{*} The power dissipation P_D is based on $T_{J(max)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit





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